

Atty. Docket No. 29925/39911

Inventor: Dae-Wook Hong
Title: Method for Manufacturing a Bipolar Transistor

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FIG. 1a (PRIOR ART)

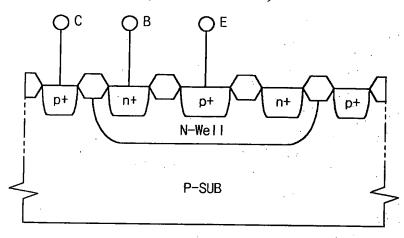
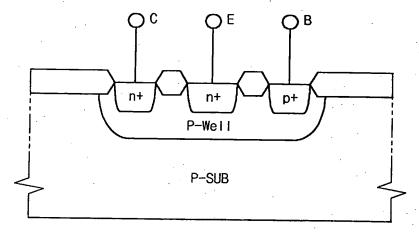


FIG. 1b (PRIOR ART)

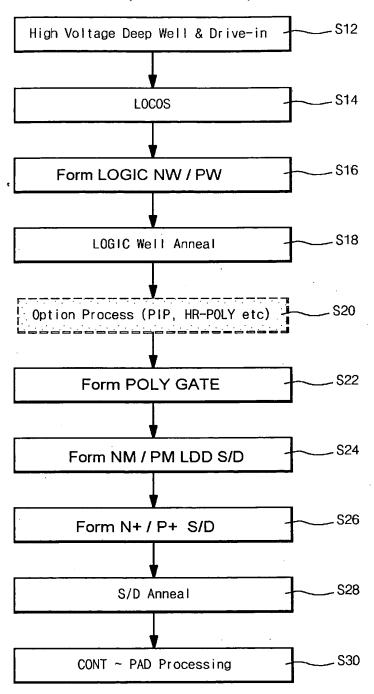


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FIG. 2 (PRIOR ART)



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FIG. 3

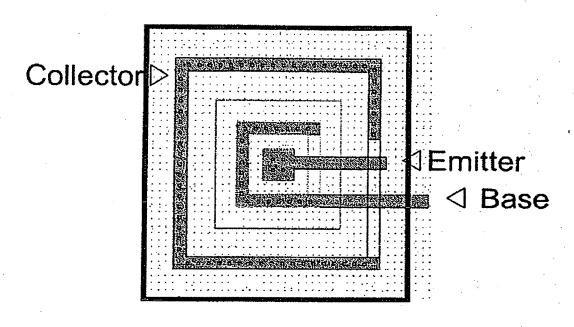
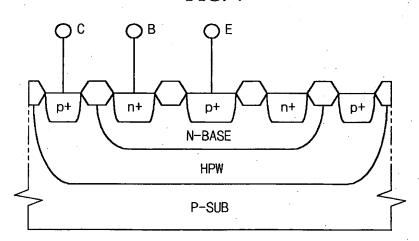


FIG. 4

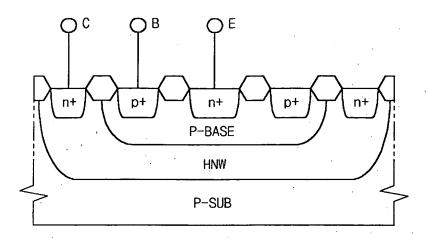


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FIG. 5

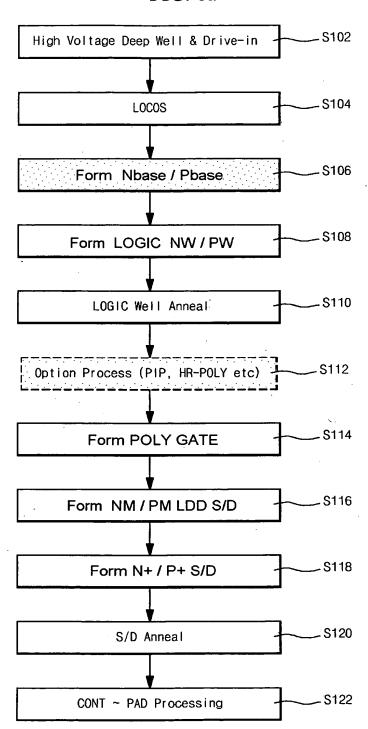


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FIG. 6a

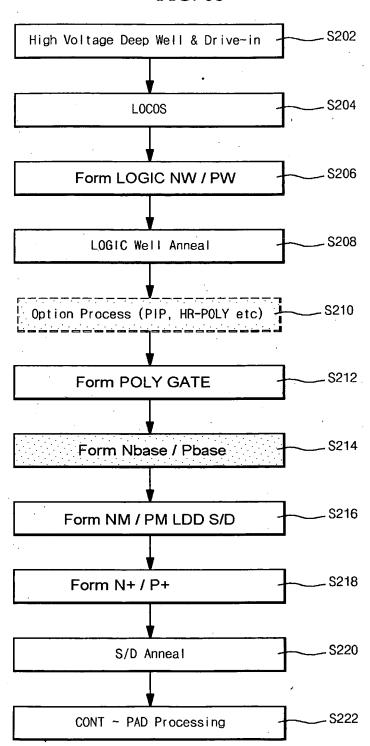


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FIG. 6b



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FIG. 7

